

Description

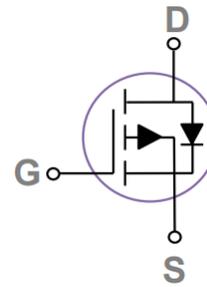
The JTD2307A uses advanced trench technology to provide excellent $R_{DS(ON)}$ and low gate charge. It can be used in a wide variety of applications.

General Features

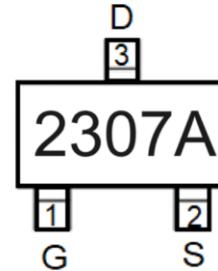
- ◆ $V_{DS} = -20V$, $I_D = -10A$
- ◆ $R_{DS(ON)} : 16.8m\Omega$ (Typ.) @ $V_{GS} = -4.5V$
- ◆ $R_{DS(ON)} : 20.8m\Omega$ (Typ.) @ $V_{GS} = -2.5V$
- ◆ High Power and current handing capability
- ◆ Lead free product is acquired
- ◆ Surface Mount Package

Application

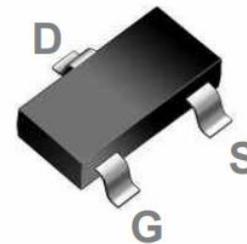
- ◆ PWM applications
- ◆ Load switch
- ◆ Power management



Schematic diagram



Marking and Pin Assignment



SOT23-3L Top view

Absolute Maximum Ratings ($T_A = 25^\circ C$ unless otherwise noted)

| Parameter | Symbol | Limit | Unit | |
|--|----------------|---------------------|------------|---|
| Drain-Source Voltage | V_{DS} | -20 | V | |
| Gate-Source Voltage | V_{GS} | ± 12 | V | |
| Drain Current-Continuous | I_D | $T_A = 25^\circ C$ | -10 | A |
| | | $T_A = 100^\circ C$ | -8 | A |
| Pulsed Drain Current ^(Note 1) | I_{DM} | -24 | A | |
| Maximum Power Dissipation | P_D | 1.2 | W | |
| Operating Junction and Storage Temperature Range | T_J, T_{STG} | -55 to 150 | $^\circ C$ | |

Thermal Characteristics

| | | | |
|---|-------------|-----|--------------|
| Thermal Resistance, Junction-to-Ambient ^(Note 2) | $R_{th JA}$ | 100 | $^\circ C/W$ |
|---|-------------|-----|--------------|

Electrical Characteristics (T_A=25°C unless otherwise noted)

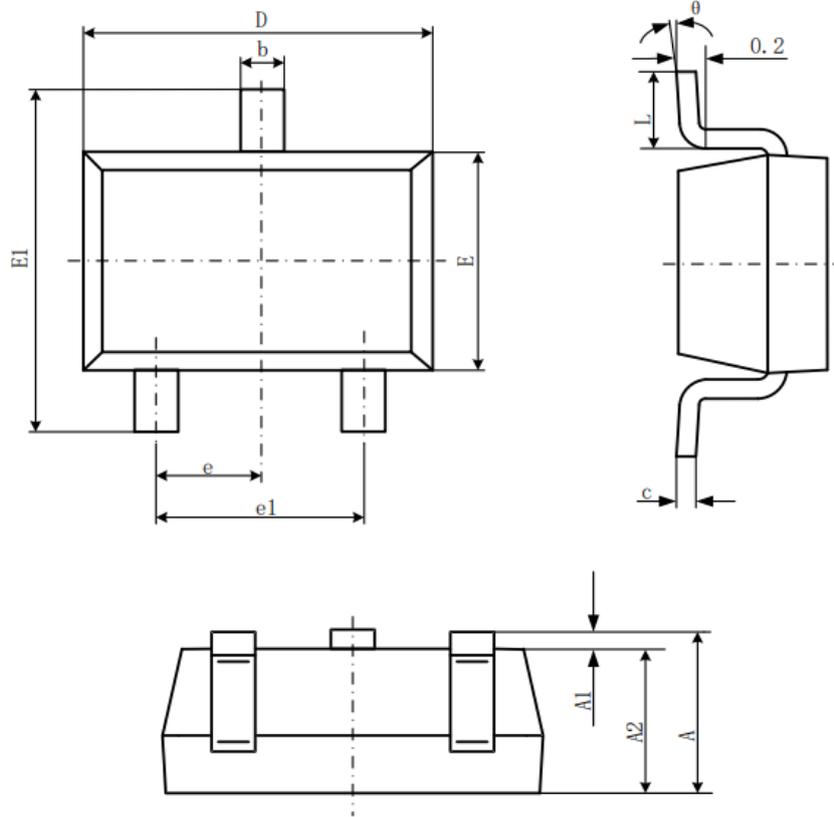
| Parameter | Symbol | Condition | Min. | Typ. | Max. | Unit |
|--|---------------------|--|------|-------|------|------|
| Off Characteristics | | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | V _{GS} =0V, I _D =250μA | -20 | - | - | V |
| Zero Gate Voltage Drain Current | I _{DSS} | V _{DS} =-20V, V _{GS} =0V | - | - | -1 | μA |
| Gate-Body Leakage | I _{GSS} | V _{GS} =±12V, V _{DS} =0V | - | - | ±100 | nA |
| On Characteristics ^(Note 3) | | | | | | |
| Gate Threshold Voltage | V _{GS(th)} | V _{DS} =V _{GS} , I _D =250μA | -0.4 | -0.68 | -1.0 | V |
| Drain-Source On-State Resistance | R _{DS(ON)} | V _{GS} =4.5V, I _D =-5A | - | 16.8 | 19.5 | mΩ |
| | | V _{GS} =2.5V, I _D =-3A | - | 20.8 | 25 | |
| Forward Transconductance | g _{FS} | V _{DS} =-5V, I _D =-5A | - | 5 | - | S |
| Dynamic Characteristics ^(Note 4) | | | | | | |
| Input Capacitance | C _{ISS} | V _{DS} =-6V V _{GS} =0V f=1.0MHz | - | 1280 | - | pF |
| Output Capacitance | C _{OSS} | | - | 300 | - | pF |
| Reverse Transfer Capacitance | C _{RSS} | | - | 280 | - | pF |
| Switching Characteristics | | | | | | |
| Turn-On Delay Time | t _{D(ON)} | V _{DD} = -10V R _L = 10 Ω I _D = -2.8A, V _{GEN} = -4.5V R _G = 6 Ω | - | 15 | - | ns |
| Rise Time | t _r | | - | 60 | - | ns |
| Turn-Off Delay Time | t _{D(OFF)} | | - | 70 | - | ns |
| Fall Time | t _f | | - | 65 | - | ns |
| Total Gate Charge | Q _g | V _{DS} =-10V, I _D =-5A, V _{GS} =-4.5V | - | 14 | - | nC |
| Gate-Source Charge | Q _{gs} | | - | 3 | - | nC |
| Gate-Drain Charge | Q _{gd} | | - | 3.5 | - | nC |
| Drain-Source Diode Characteristics ^(Note 3) | | | | | | |
| Diode forward voltage | V _{SD} | V _{GS} =0V, I _S =-1.25A | | -0.76 | -1.2 | V |

Notes

- 1.Repetitive Rating: Pulse width limited by maximum junction temperature.
2. Surface Mounted on FR4 Board, t ≤ 10sec.
3. Pulse Test: PulseWidth ≤ 300uS, Duty Cycle ≤ 2%
4. Guaranteed by design, not subject to production testing.

Package Information

SOT23-3L



| Symbol | Dimensions In Millimeters | | Dimensions In Inches | |
|----------|---------------------------|-------|----------------------|-------|
| | Min | Max | Min | Max |
| A | 1.050 | 1.250 | 0.041 | 0.049 |
| A1 | 0.000 | 0.100 | 0.000 | 0.004 |
| A2 | 1.050 | 1.150 | 0.041 | 0.045 |
| b | 0.300 | 0.500 | 0.012 | 0.020 |
| c | 0.100 | 0.200 | 0.004 | 0.008 |
| D | 2.820 | 3.020 | 0.111 | 0.119 |
| E | 1.500 | 1.700 | 0.059 | 0.067 |
| E1 | 2.650 | 2.950 | 0.104 | 0.116 |
| e | 0.950(BSC) | | 0.037(BSC) | |
| e1 | 1.800 | 2.000 | 0.071 | 0.079 |
| L | 0.300 | 0.600 | 0.012 | 0.024 |
| θ | 0° | 8° | 0° | 8° |